

CTLTVS12

**SURFACE MOUNT SILICON
UNI-DIRECTIONAL
TRANSIENT VOLTAGE SUPPRESSOR**



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CTLTVS12 is a low leakage, fast response TVS packaged in an ultra small, ultra low profile surface mount package. This device is designed to protect sensitive equipment against ESD damage.

MARKING CODE: O



APPLICATIONS:

- PDAs
- Memory Card Ports
- Cellular Phones
- Instrumentation

FEATURES:

- Ultra Small, Ultra Low Profile 0.3mm x 0.6mm x 0.3mm Leadless Surface Mount package
- Low Capacitance
- Low Leakage Current

MAXIMUM RATINGS: (T_A=25°C)

Peak Power Dissipation (8x20µs)
 Electrical Fast Transient (IEC 61000-4-4) (5x50ns)
 ESD Voltage (IEC 61000-4-2, Air)
 ESD Voltage (IEC 61000-4-2, Contact)
 Operating and Storage Junction Temperature

SYMBOL

P_{PK}
 EFT
 V_{ESD}
 V_{ESD}
 T_J, T_{stg}

UNITS

W
 A
 kV
 kV
 °C

ELECTRICAL CHARACTERISTICS: (T_A=25°C) V_F=1.0V MAX @ I_F=10mA

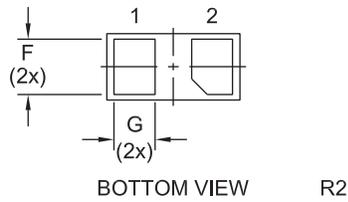
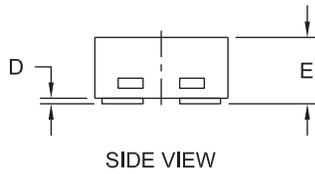
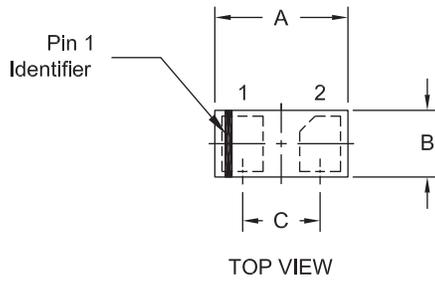
Maximum Reverse Stand-off Voltage V _{RWM}	Breakdown Voltage V _{BR} @ I _T			Test Current I _T	Maximum Reverse Leakage Current I _R @ V _{RWM}	Maximum Clamping Voltage (8x20µs) V _C @ I _{PP}		Typical TLP Clamping Voltage (Note 1) V _{CL} @ I _{PP}		Typical Dynamic Resistance (Note 1) R _{DYN}	Typical Junction Capacitance @ 0V Bias C _J	Typical Junction Capacitance @ 9V Bias C _J
	V	MIN V	NOM V			MAX V	V	A	V			
9.0	10	12	14	5.0	1.0	18	1.8	6.0	6.0	0.71	14	5.0
								11	13			

Note 1: Transmission Line Pulse (TLP) conditions: Z₀=50Ω, t_p=100ns


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TLM2D3D6 CASE - MECHANICAL OUTLINE



SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.022	0.026	0.55	0.65
B	0.010	0.014	0.25	0.35
C	0.014		0.35	
D	0.000	0.002	0.00	0.05
E	0.011	0.013	0.28	0.32
F	0.008	0.012	0.20	0.30
G	0.005	0.009	0.13	0.24

TLM2D3D6 (REV: R2)

LEAD CODE:
 1) Cathode
 2) Anode

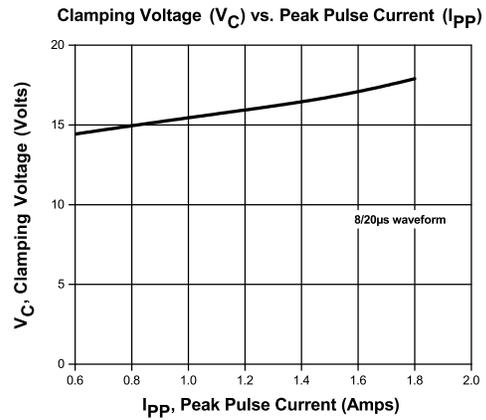
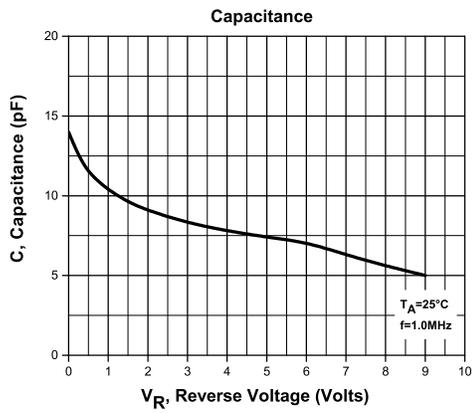
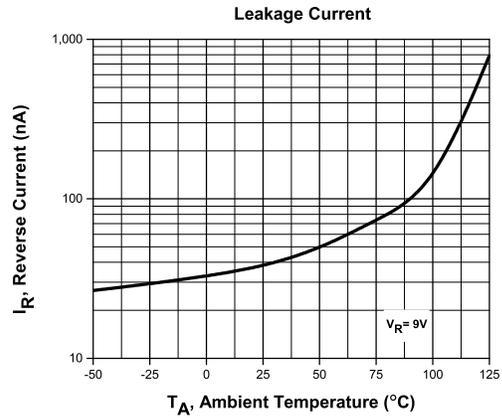
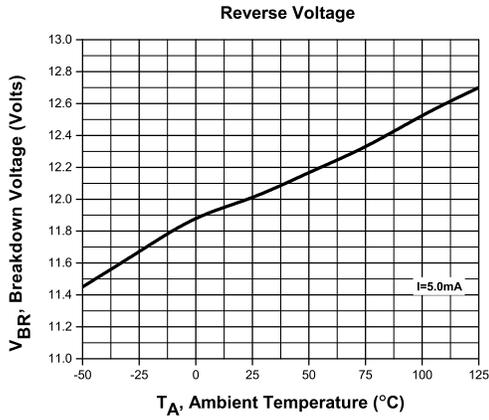
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R3 (23-October 2015)


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TYPICAL ELECTRICAL CHARACTERISTICS

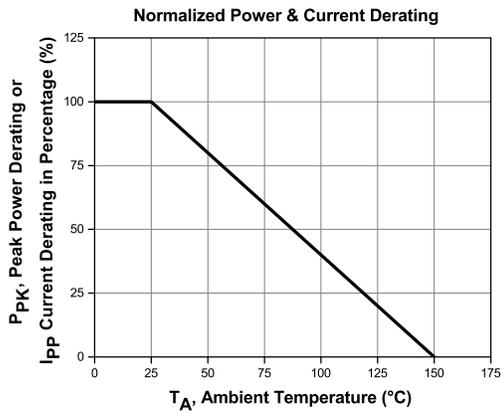
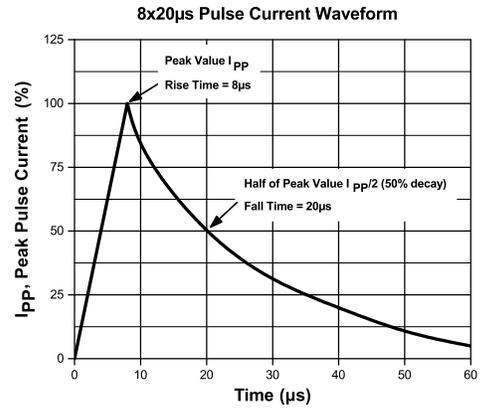
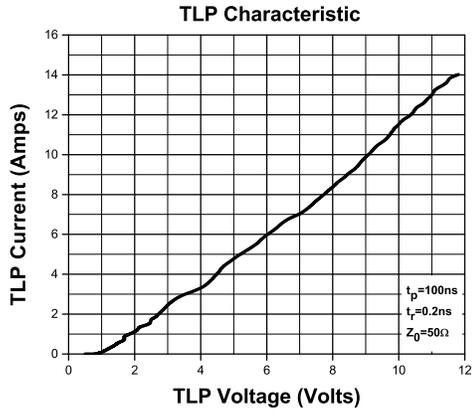


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TYPICAL ELECTRICAL CHARACTERISTICS



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OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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